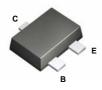


November 2006

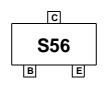
FJY4006R PNP Epitaxial Silicon Transistor

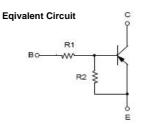
Features

- · Switching circuit, Inverter, Interface circuit, Driver Circuit
- Built in bias Resistor (R₁=10K Ω , R₂=47K Ω)
- Complement to FJY3006R









Absolute Maximum Ratings * T_a = 25°C unless otherwise noted

| Symbol | Parameter | Value | Units |
|------------------|---|---------|-------|
| V _{CBO} | Collector-Base Voltage | -50 | V |
| V _{CEO} | Collector-Emitter Voltage | -50 | V |
| V _{EBO} | Emitter-Base Voltage | -10 | V |
| I _C | Collector Current | -100 | mA |
| T _{STG} | Storage Temperature Range | -55~150 | °C |
| T _J | Junction Temperature | 150 | °C |
| P _C | Collector Power Dissipation, by $R_{\theta JA}$ | 200 | mW |

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may by impaired.

Thermal Characteristics* Ta=25°C unless otherwise noted

| Symbol Parameter | Max | Units | |
|--|-----|-------|--|
| R _{0JA} Thermal Resistance, Junction to Ambient | 600 | °C/W | |

Electrical Characteristics* T_C = 25°C unless otherwise noted

| Symbol | Parameter | Test Condition | MIN | Тур | MAX | Units |
|--------------------------------|--------------------------------------|---------------------------------------|------|------|------|-------|
| V _(BR) CBO | Collector-Emitter Breakdown Voltage | Ic = -10 uA, IE = 0 | -50 | | | V |
| V _(BR) CEO | Collector-Base Breakdown Voltage | Ic = -100 uA, IB = 0 | -50 | | | V |
| Ісво | Collector-Cutoff Current | Vcb = -40 V, IE = 0 | | | -0.1 | uA |
| hfe | DC Current Gain | Vce = -5 V, Ic = -5mA | 68 | | | |
| VcE(sat) | Collector-Emitter Saturation Voltage | Ic = -10 mA, I _B = -0.5 mA | | | -0.3 | V |
| f⊤ | Current Gain - Bandwidth Product | VcE = -10V, Ic = -5 mA | | 200 | | MHz |
| Ccb | Output Capacitance | Vcb = -10 V, IE = 0, f = 1.0 MHz | | 5.5 | | pF |
| Vı(off) | Input Off Voltage | Vce = -5 V, Ic = -100uA | -0.3 | | | V |
| V _I (on) | Input On Voltage | VcE = -0.3V, Ic = -1mA | | | -1.4 | V |
| R ₁ | Input Resistor | | 7 | 10 | 13 | ΚΩ |
| R ₁ /R ₂ | Resistor Ratio | | 0.19 | 0.21 | 0.24 | |

^{*} Pulse Test: PW≤300μs, Duty Cycle≤2%

Typical Performance Characteristics

Figure 1. DC current Gain

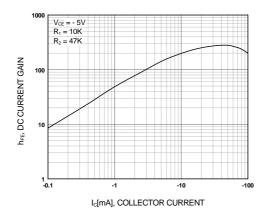


Figure 3. Input off Voltage

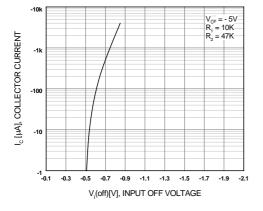


Figure 2. Input On Voltage

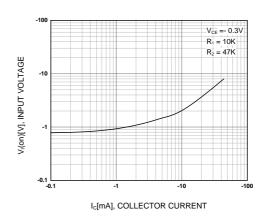
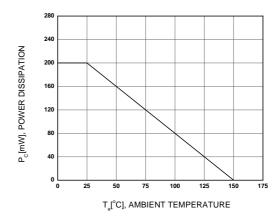


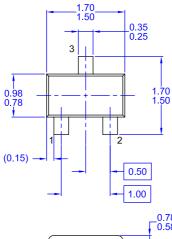
Figure 4. Power Derating

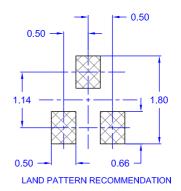


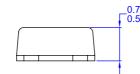
2

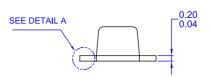
Package Dimensions

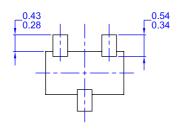
SOT-523F

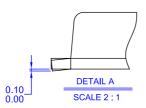












- NOTES: UNLESS OTHERWISE SPECIFIED A) THIS PACKAGE CONFORMS TO EIAJ SC89 PACKAGING STANDARD.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
 C) DIMENSIONS ARE EXCLUSIVE OF BURRS,
 MOLD FLASH, AND TIE BAR EXTRUSIONS.

Dimensions in Millimeters



FAIRCHILD SEMICONDUCTOR TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACFx™ FACT Quiet Series™ SILENT SWITCHER® UniFET™ ActiveArray[™] GlobalOptoisolator™ $OCXPro^{TM}$ SMART START™ VCX™ OPTOLOGIC® SPM™ Wire™ Bottomless™ GTO™ Build it Now™ HiSeC™ OPTOPLANAR™ Stealth™ CoolFET™ I²C™ PACMAN™ SuperFET™ CROSSVOLT™ i-Lo™ POP™ SuperSOT™-3 Power247™ DOME™ ImpliedDisconnect™ SuperSOT™-6 PowerEdge™ EcoSPARK™ SuperSOT™-8 IntelliMAX™ E^2CMOS^\intercal ISOPLANAR™ PowerSaver™ SyncFET™ PowerTrench® TCM™ EnSigna™ LittleFET™ FACT[®] MICROCOUPLER™ QFET[®] TinyBoost™ $\mathsf{FAST}^{\circledR}$ QS™ MicroFET™ TinyBuck™ $\operatorname{TinyPWM^{\intercal M}}$ $\mathsf{FASTr}^{\mathsf{TM}}$ QT Optoelectronics™ MicroPak™ FPS™ TinyPower™ MICROWIRE™ Quiet Series™ RapidConfigure™ TinyLogic[®] FRFET™ MSX™ MSXPro™ RapidConnect™ TINYOPTO™ µSerDes™ TruTranslation™ Across the board. Around the world.™ **UHC®** The Power Franchise® ScalarPump™ Programmable Active Droop™

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION, OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS. THESE SPECIFICATIONS DO NOT EXPAND THE TERMS OF FAIRCHILD'S WORLDWIDE TERMS AND CONDITIONS, SPECIFICALLY THE WARRANTY THEREIN, WHICH COVERS THESE PRODUCTS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.

As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

| Datasheet Identification | Product Status | Definition | | |
|--------------------------|------------------------|--|--|--|
| Advance Information | Formative or In Design | This datasheet contains the design specifications for product development. Specifications may change in any manner without notice. | | |
| Preliminary | First Production | This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design. | | |
| No Identification Needed | Full Production | This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design. | | |
| Obsolete | Not In Production | This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only. | | |